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# Dual Ultralow Distortion, Ultralow Noise Op Amp

## AD8599

### FEATURES

**Low noise:** 1 nV/ $\sqrt{\text{Hz}}$  at 1kHz  
**Low distortion:**  $-105 \text{ dB THD} @ 20 \text{ kHz}$   
**<80 nV p-p input noise, 0.1 Hz to 10 Hz**  
**Slew rate:** 16 V/ $\mu\text{s}$   
**Wide bandwidth:** 10 MHz  
**Supply current:** 4.7 mA/amp typical  
**Low offset voltage:** 10  $\mu\text{V}$  typical  
**CMRR:** 120 dB  
**Unity-gain stable**  
 **$\pm 15 \text{ V}$  operation**

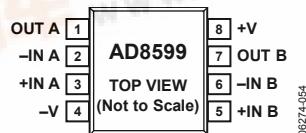
### APPLICATIONS

**Professional audio preamplifiers**  
**ATE/precision testers**  
**Imaging systems**  
**Medical/physiological measurements**  
**Precision detectors/instruments**  
**Precision data conversion**

### GENERAL DESCRIPTION

The AD8599 is a dual, very low noise, low distortion operational amplifier ideal for use as a preamplifier. The low noise of 1 nV/ $\sqrt{\text{Hz}}$  and low harmonic distortion of  $-105 \text{ dB}$  (or better) at audio bandwidths give the AD8599 the wide dynamic range necessary for preamps in audio, medical, and instrumentation applications. The AD8599's excellent slew rate of 16 V/ $\mu\text{s}$  and

### FUNCTIONAL BLOCK DIAGRAM



10 MHz gain bandwidth make it highly suitable for medical applications. The low distortion and settling time of the AD8599 make it ideal for buffering of high resolution data converters.

The AD8599 is available in an 8-Lead SOIC package and is specified over the  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$  temperature range.

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## REVISION HISTORY

2/07—Revision 0: Initial Version

## SPECIFICATIONS

$V_S = \pm 15$  V,  $V_{CM} = 0$  V,  $V_O = 0$  V,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		10	120	$\mu\text{V}$
					180	$\mu\text{V}$
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		0.8	2.2	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		25	180	nA
					300	nA
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		25	180	nA
					220	nA
Input Voltage Range	IVR	$V_{DD} = \pm 15$ V		-12.5	+12.5	V
Common-Mode Rejection Ratio	CMRR	$-12.5$ V $\leq V_{CM} \leq +12.5$ V		120	140	dB
		$-40^\circ\text{C} \leq T_A \leq 125^\circ\text{C}$		115		dB
Large Signal Voltage Gain	$A_V$	$R_L \geq 600 \Omega$ , $V_O = -11$ V to +11 V		110	116	dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		106		dB
Input Capacitance	$C_{DIFF}$				4.8	pf
	$C_{CM}$				4.5	pf
OUTPUT CHARACTERISTICS						
Output Voltage High	$V_{OH}$	$R_L = 600 \Omega$	13.1	13.4		V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	12.8			V
		$R_L = 2 \text{ k}\Omega$	13.5	13.7		V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	13.2			V
Output Voltage Low	$V_{OL}$	$R_L = 600 \Omega$		-13.2	-12.9	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-12.8	V
		$R_L = 2 \text{ k}\Omega$		-13.5	-13.4	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-13.3	V
Output Source Circuit	$I_{SC}$				$\pm 52$	mA
Closed-Loop Output Impedance	$Z_{OUT}$	At 1 MHz, $A_V = +1$			5	$\Omega$
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{DD} = \pm 18$ V to $\pm 4.5$ V	120	140		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	118			dB
Supply Current per Amplifier	$I_{SY}$			4.7	5.7	mA
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			6.75	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$A_V = -1$ , $R_L = 2 \text{ k}\Omega$			16.8	$\text{V}/\mu\text{s}$
		$A_V = 1$ , $R_L = 2 \text{ k}\Omega$			15	$\text{V}/\mu\text{s}$
Settling Time	$t_s$	To 0.01%, step = 10 V			2	$\mu\text{s}$
Gain Bandwidth Product	GBP				10	MHz
Phase Margin	$\phi_M$				68	Degrees
NOISE PERFORMANCE						
Peak-to-Peak Noise	$e_n$ p-p	0.1 Hz to 10 Hz			76	nV
Voltage Noise Density	$e_n$	$f = 1$ kHz			1.07	$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10$ Hz				$\text{nV}/\sqrt{\text{Hz}}$
Current Noise		$f = 1$ kHz			1.5	$\text{pA}/\sqrt{\text{Hz}}$
Total Harmonic Distortion + Noise	THD + N	$G = 1$ , $R_L \geq 1 \text{ k}\Omega$ , $f = 1$ kHz, $V_{RMS} = 3$ V, $\pm 15$ V			-108	dB
		$G = 1$ , $R_L \geq 1 \text{ k}\Omega$ , $f = 20$ kHz, $V_{RMS} = 3$ V, $\pm 15$ V			-105	dB
Channel Separation	CS	$f = 10$ kHz			-120	dB

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## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage	$\pm 18\text{ V}$
Input Voltage	GND to $V_{DD}$
Differential Input Voltage	$\pm 1\text{ V}$
Output Short-Circuit to GND	Indefinite
Storage Temperature Range	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Operating Temperature Range	$-40^\circ\text{C}$ to $+125^\circ\text{C}$
Lead Temperature Range (Soldering 60 sec)	300°C
Junction Temperature	150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
8-Lead SOIC (R-8)	120	36	°C/W

## POWER SEQUENCING

The op amp supplies must be established simultaneously with, or before, any input signals are applied.

If this is not possible, the input current must be limited to 10 mA.

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.**  
Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## TYPICAL PERFORMANCE CHARACTERISTICS

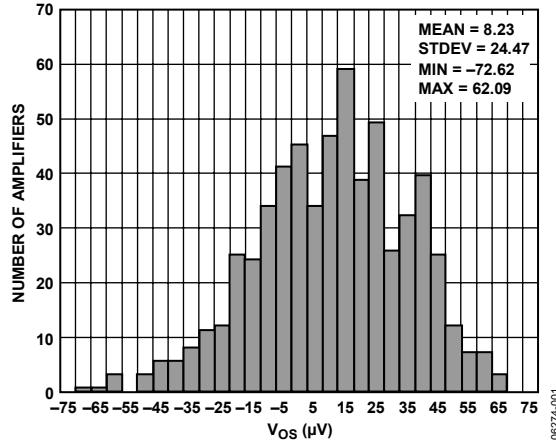


Figure 2. Input Offset Voltage Distribution  $V_S = \pm 5\text{ V}$

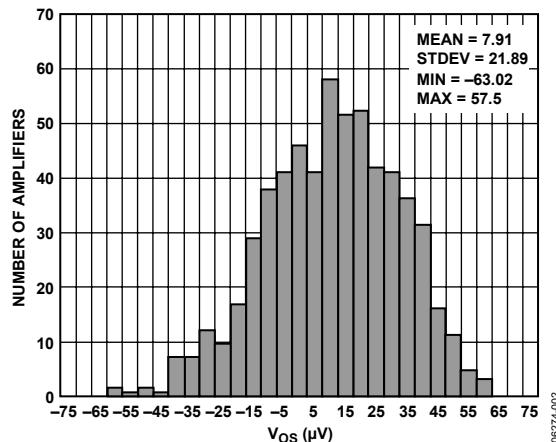


Figure 3. Input Offset Voltage Distribution  $V_S = \pm 15\text{ V}$

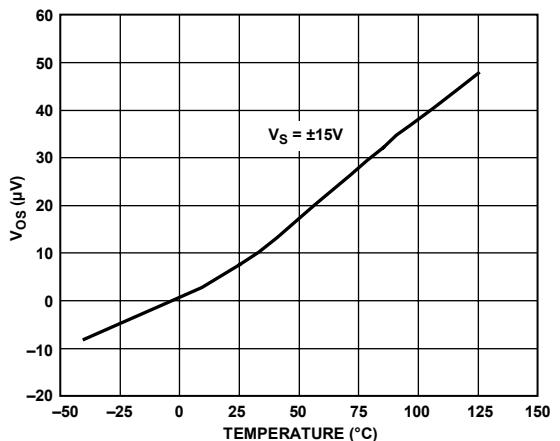


Figure 4. Input Offset Voltage vs. Temperature

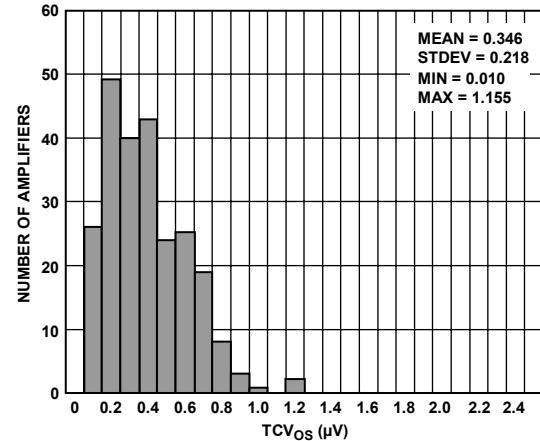


Figure 5. TCV<sub>OS</sub> Distribution  $V_S = \pm 5\text{ V}$ ,  $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$

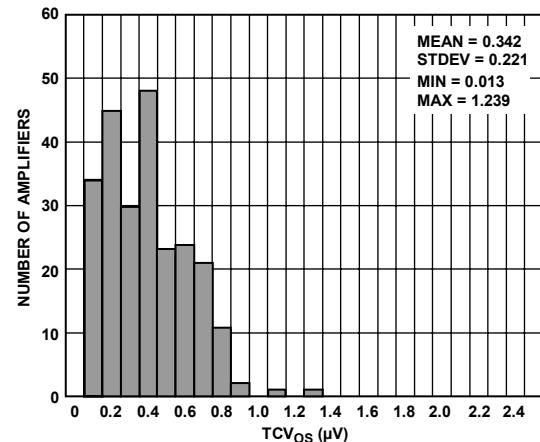


Figure 6. TCV<sub>OS</sub> Distribution  $V_S = \pm 15\text{ V}$ ,  $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$

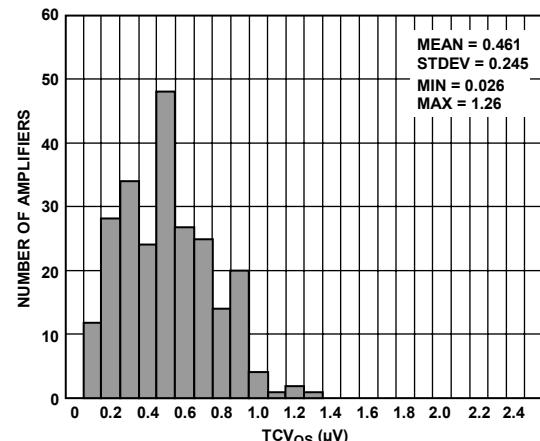


Figure 7. TCV<sub>OS</sub> Distribution  $V_S = \pm 5\text{ V}$ ,  $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$

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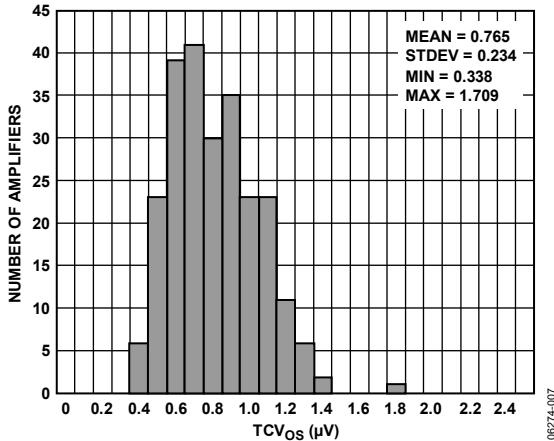


Figure 8.  $TCV_{OS}$  Distribution,  $V_S = \pm 15 V$ ,  $-40^\circ C \leq T_A \leq +125^\circ C$

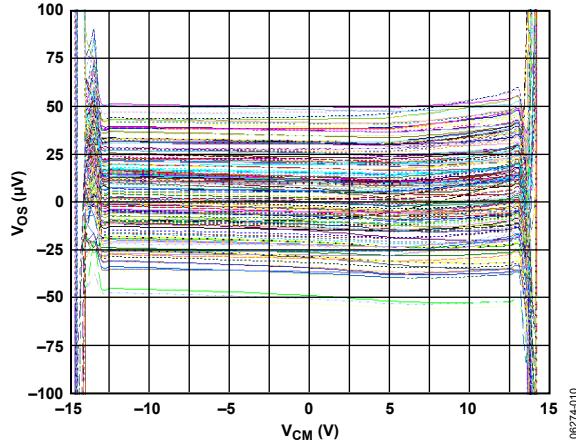


Figure 11. Offset Voltage vs.  $V_{CM}$ ,  $V_S = \pm 15 V$

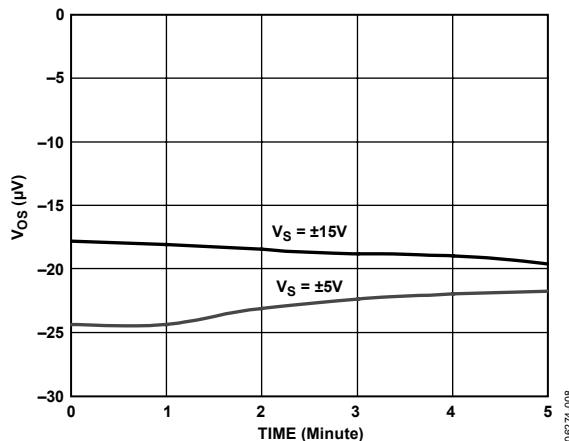


Figure 9. Offset Voltage vs. Time

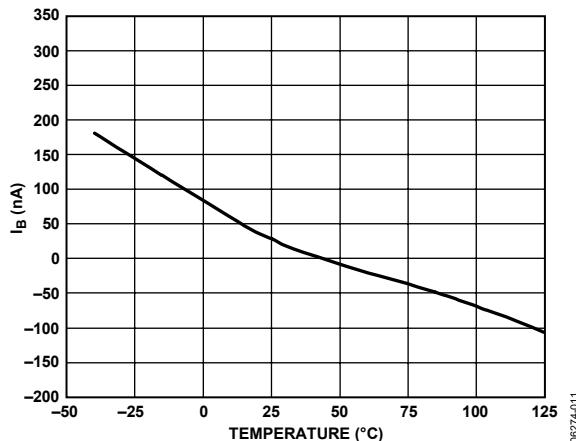


Figure 12. Input Bias Current vs. Temperature  $V_S = \pm 5 V$ ,  $V_{CM} = 0 V$

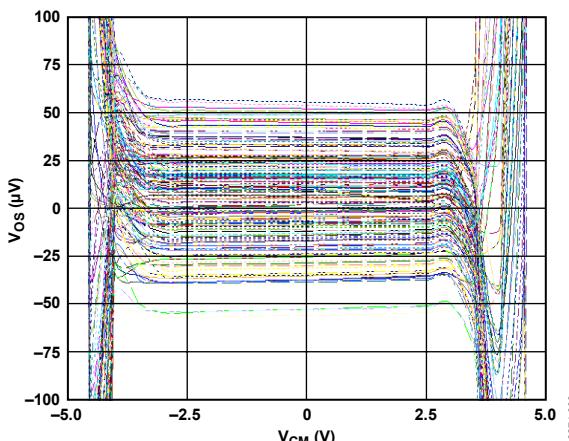


Figure 10. Offset Voltage vs.  $V_{CM}$ ,  $V_S = \pm 5 V$

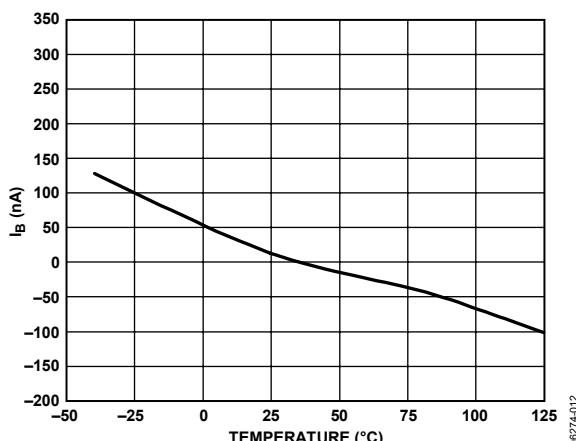


Figure 13. Input Bias Current vs. Temperature  $V_S = \pm 15 V$ ,  $V_{CM} = 0 V$

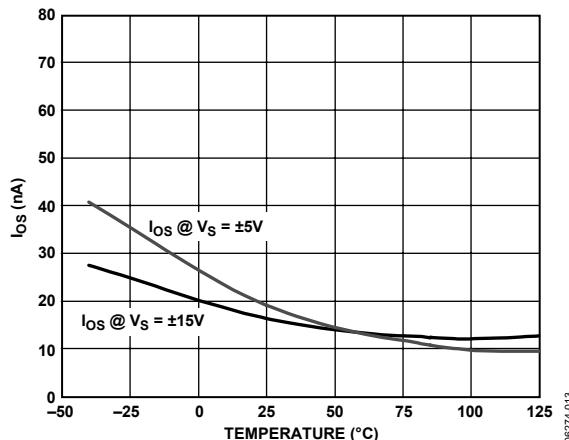
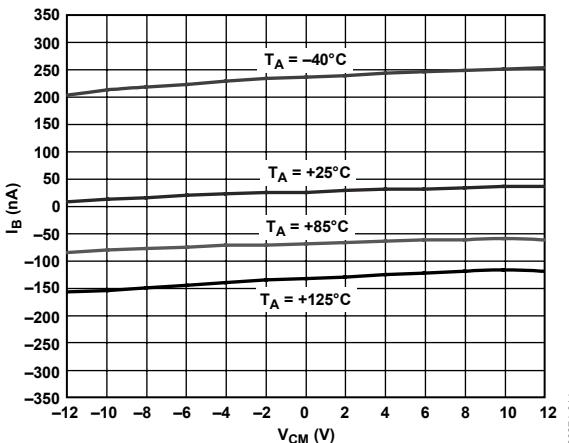
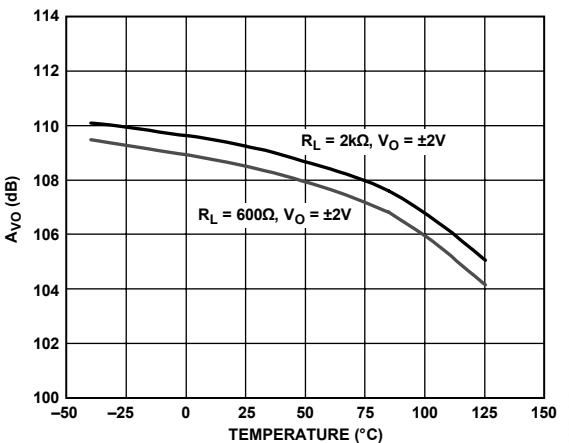
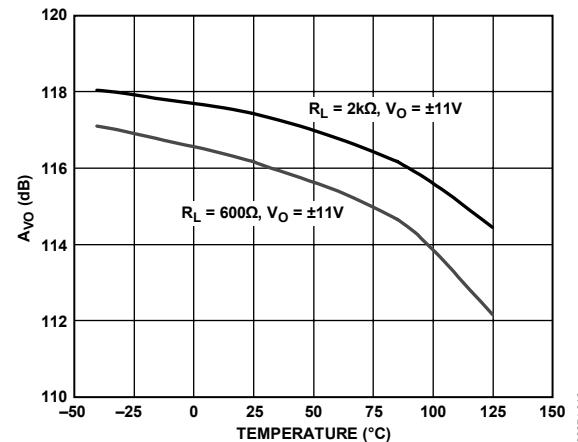
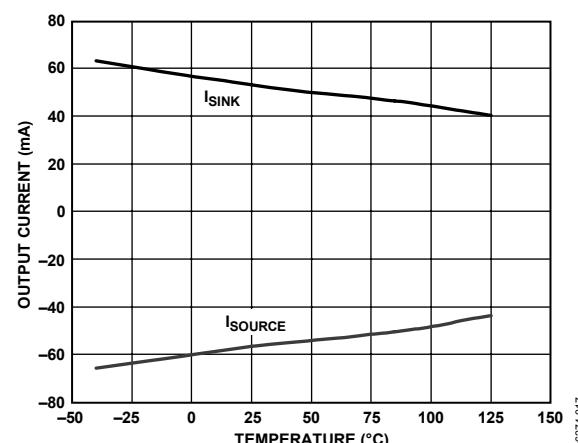
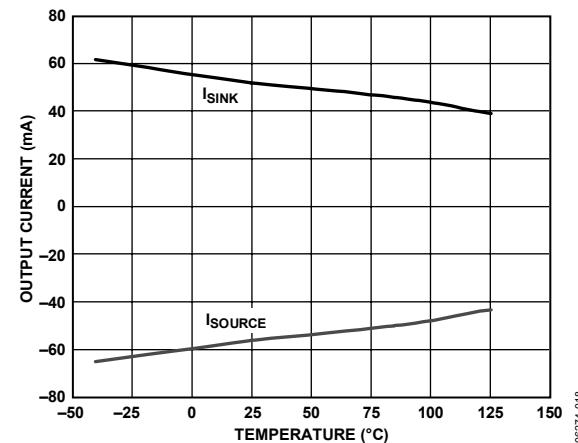
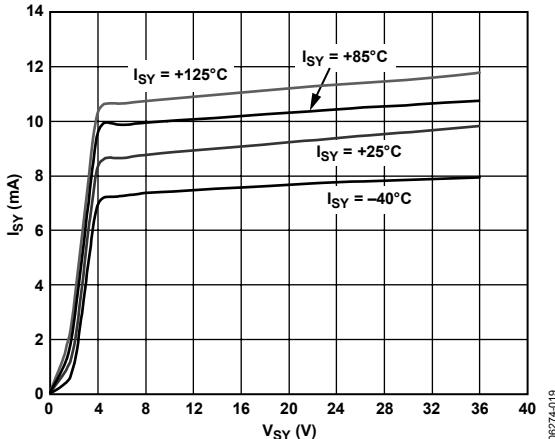


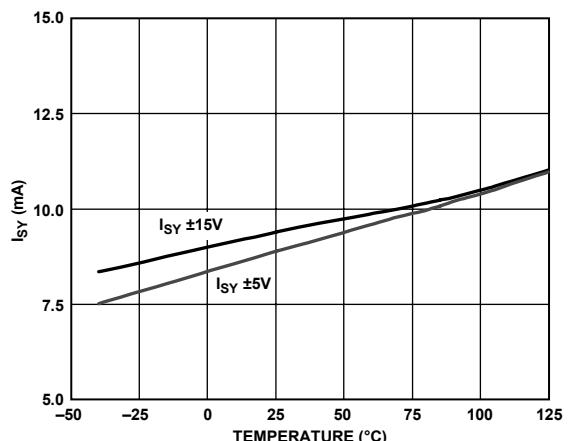
Figure 14. Input Offset Current vs. Temperature

Figure 15. Input Bias Current vs.  $V_{CM}$ ,  $V_S = \pm 15 V$ Figure 16. Large Signal Voltage Gain vs. Temperature  $V_S = \pm 5 V$ Figure 17. Large Signal Voltage Gain vs. Temperature,  $V_S = \pm 15 V$ Figure 18. Output Current vs. Temperature,  $V_S = \pm 5 V$ Figure 19. Output Current vs. Temperature,  $V_S = \pm 15 V$

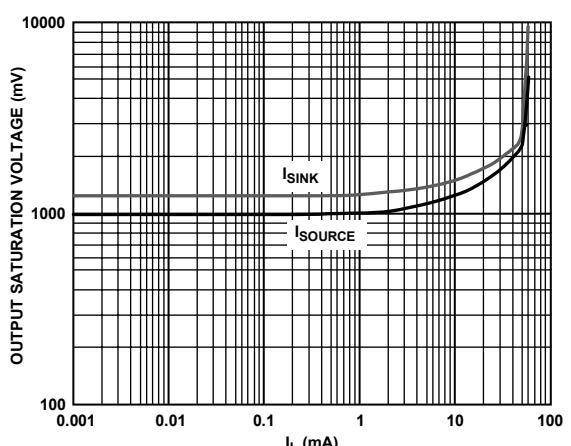
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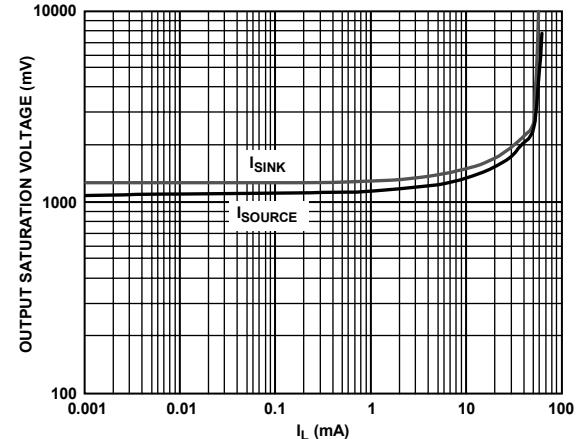
06274-019



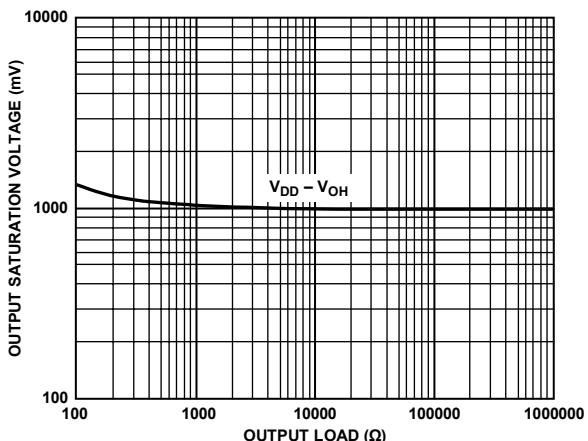
06274-020



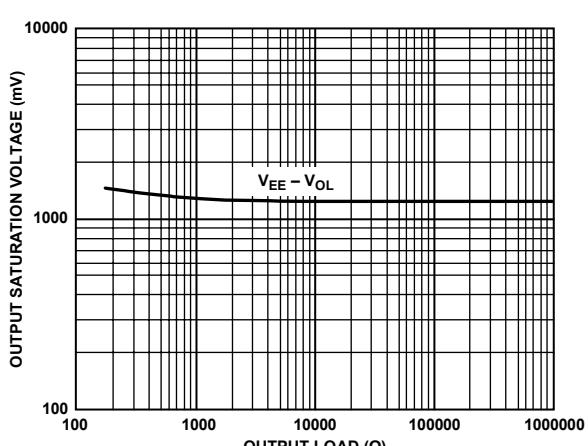
06274-021



06274-022



06274-023



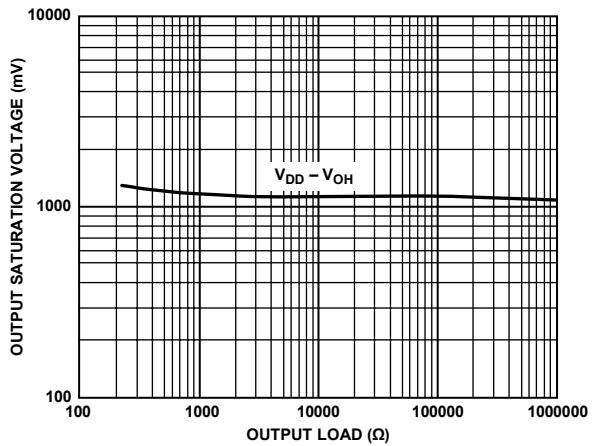
06274-024

Figure 20. Supply Current vs. Supply Voltage

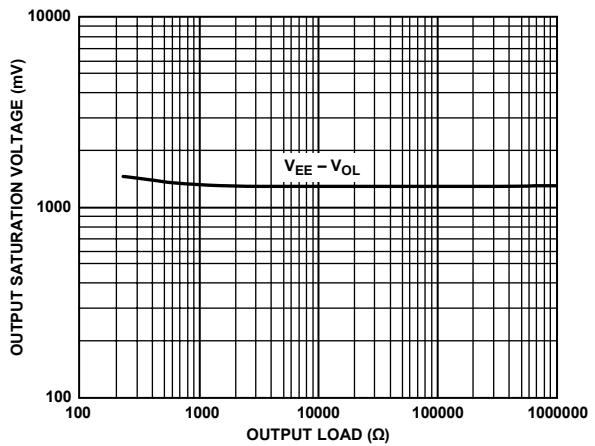
Figure 21. Supply Current vs. Temperature

Figure 22. Output Saturation Voltage vs. Current Load,  $V_S = \pm 5\text{ V}$

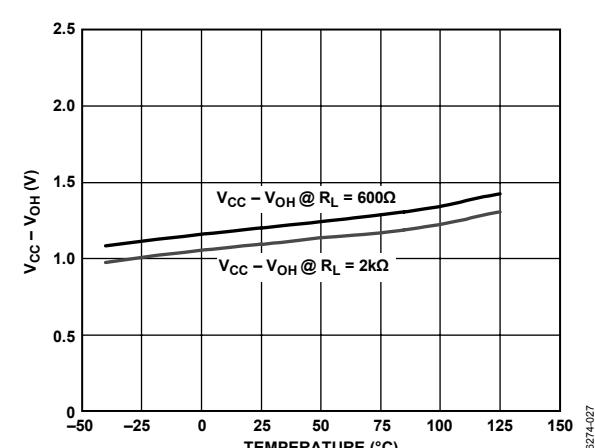
Figure 23. Output Saturation Voltage vs. Current Load,  $V_S = \pm 15\text{ V}$



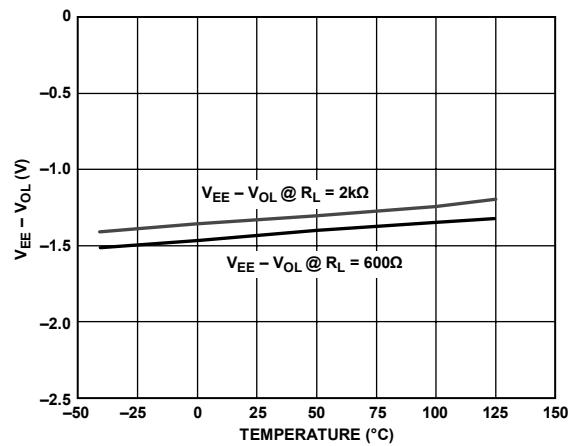
06274-025



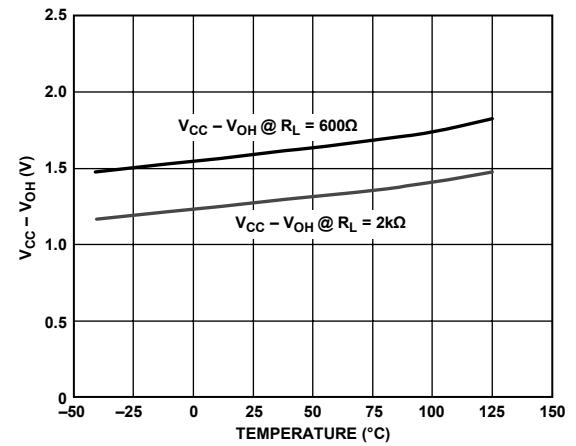
06274-026



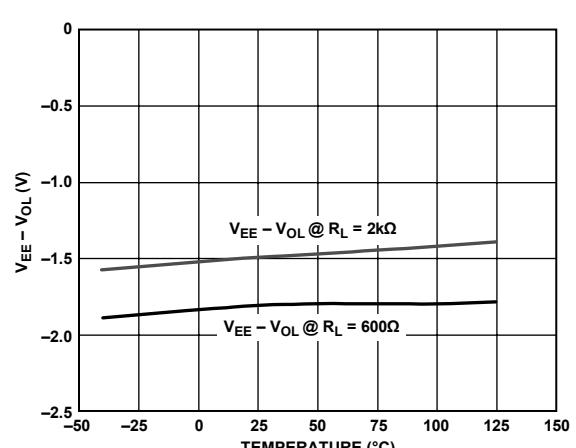
06274-027



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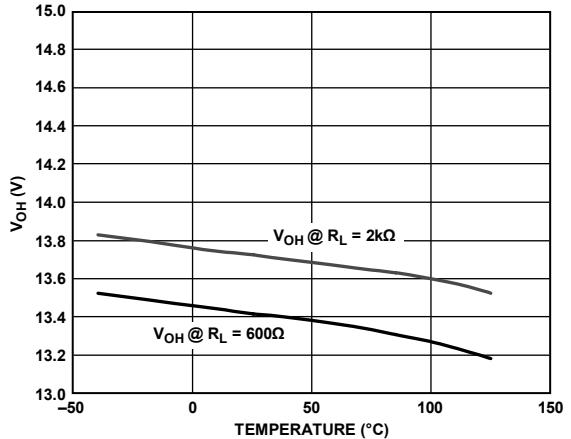
06274-029



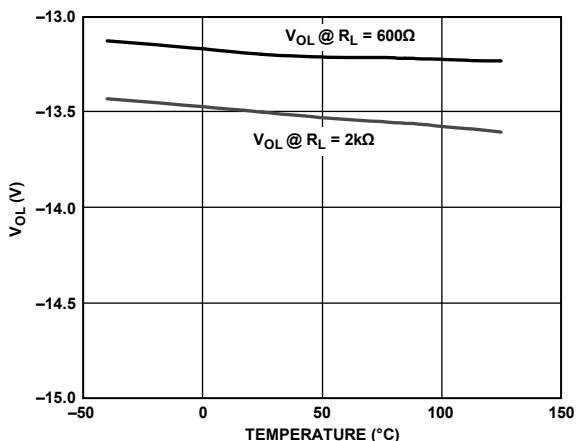
06274-030

Figure 28. Output Saturation Voltage vs. Temperature,  $V_S = \pm 5 V$ Figure 29. Output Saturation Voltage vs. Temperature,  $V_S = \pm 5 V$

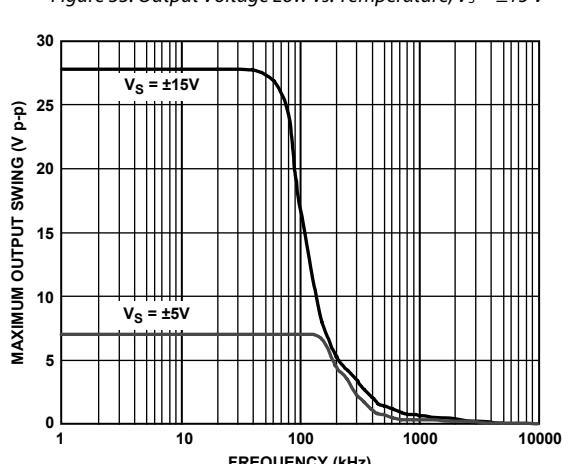
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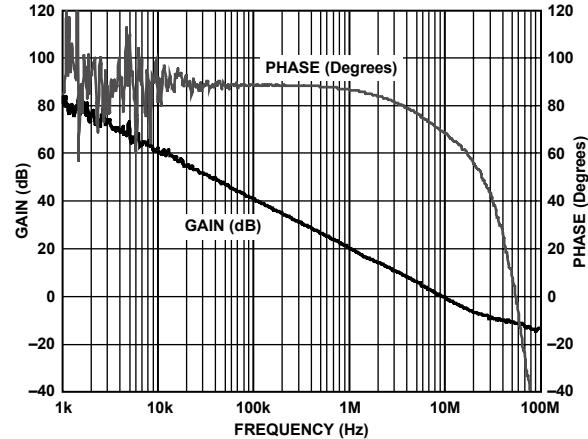
06274-031



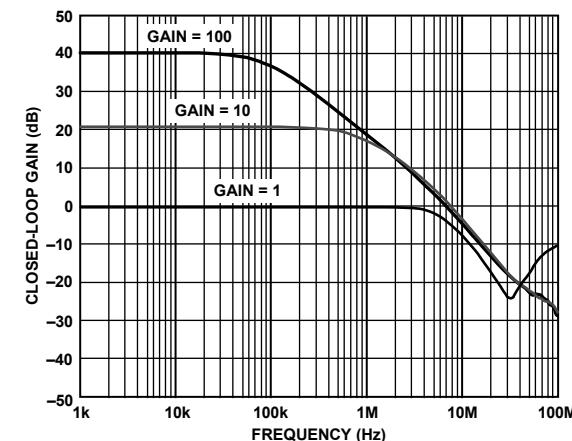
06274-032



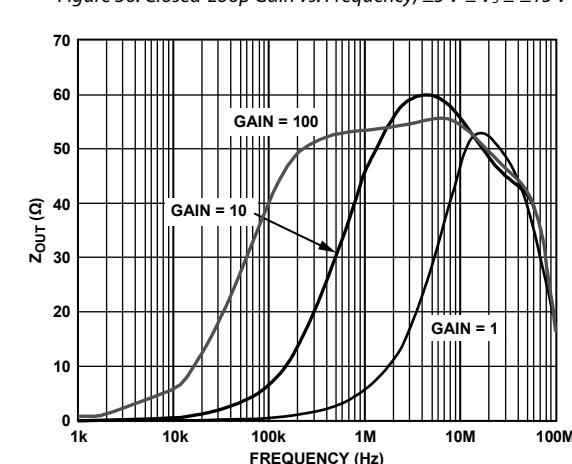
06274-033



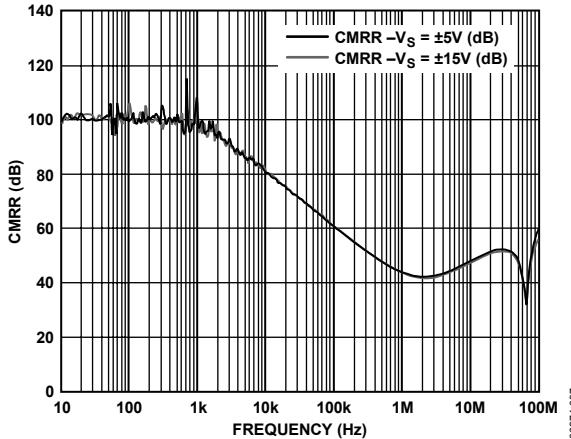
06274-034



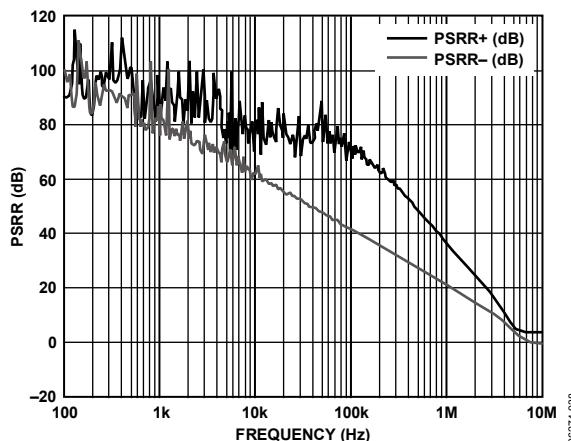
06274-035



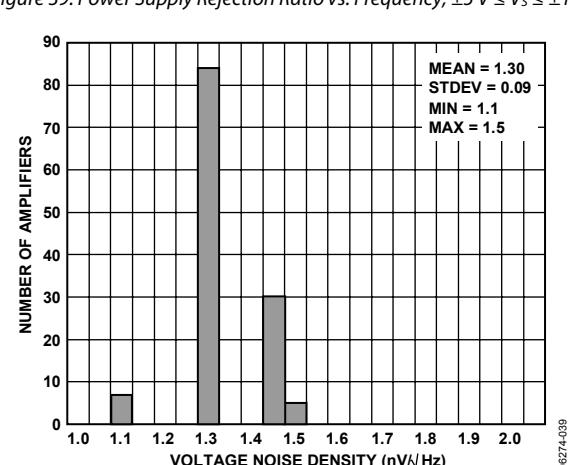
06274-036



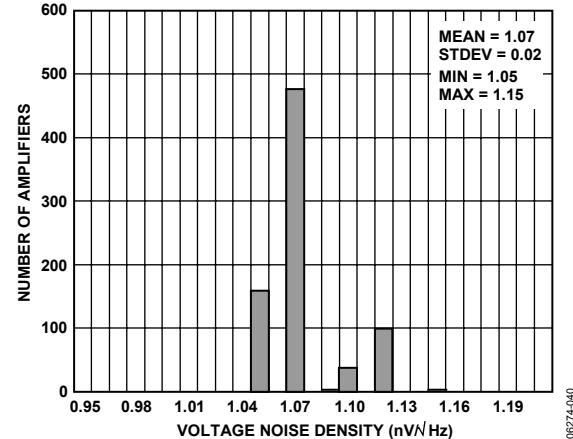
06274-037



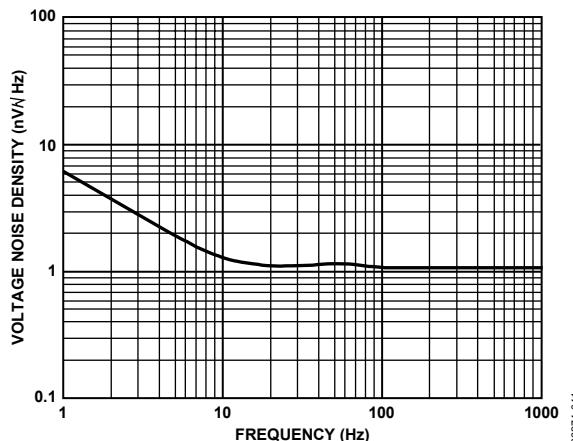
06274-038



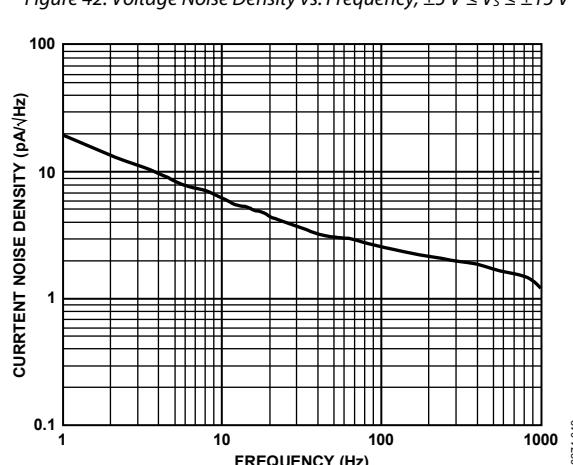
06274-039



06274-040

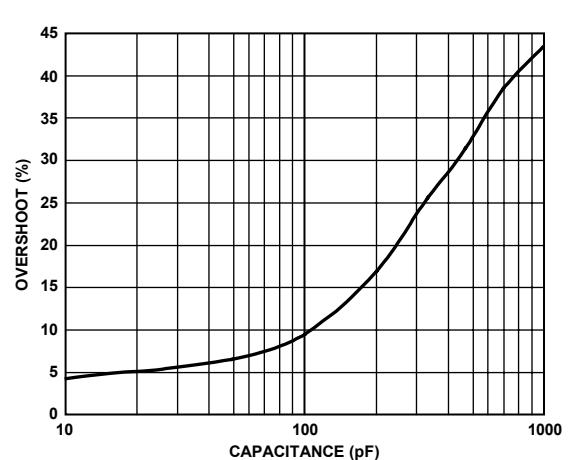
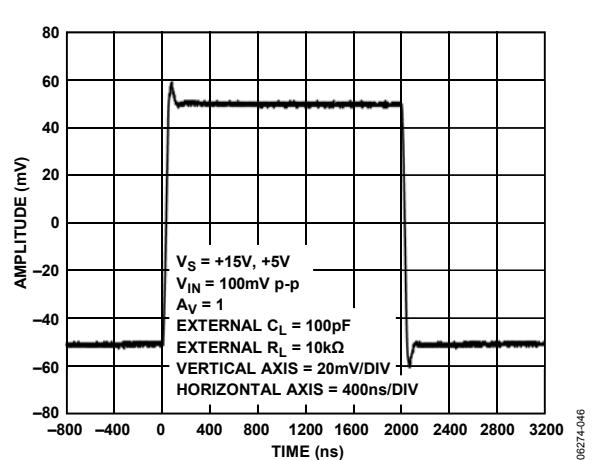
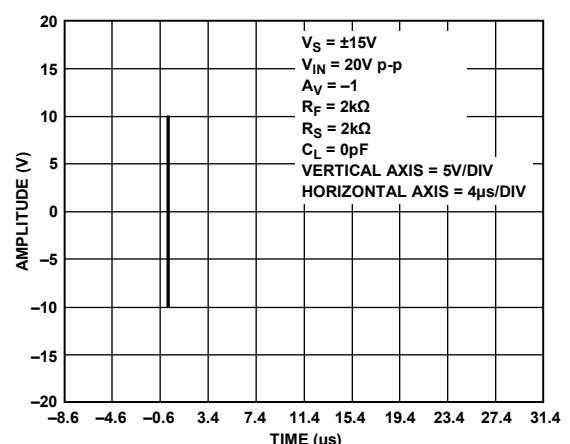
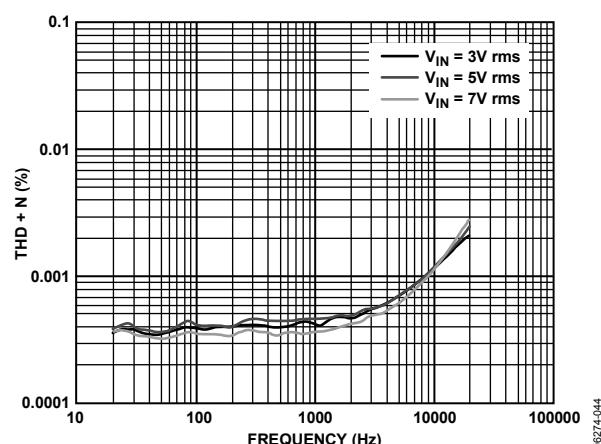
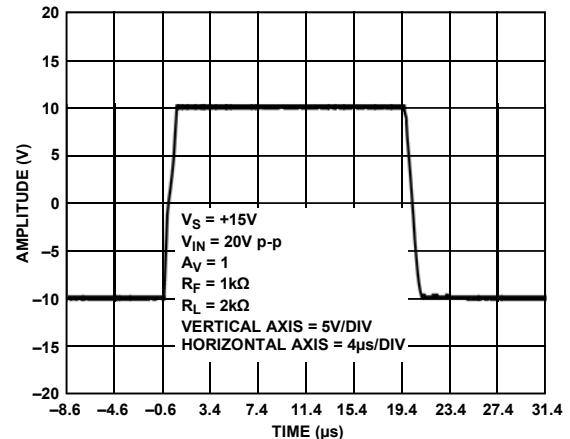
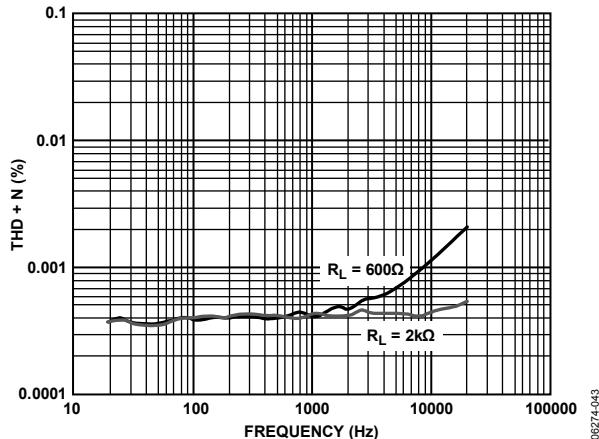


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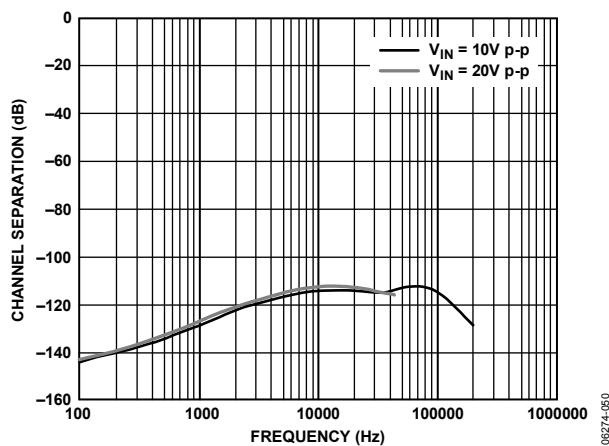


Figure 50. Channel Separation vs. Frequency,  $V_S = \pm 15 V$ ,  $A_V = 100$ ,  $R_L = 1 k\Omega$

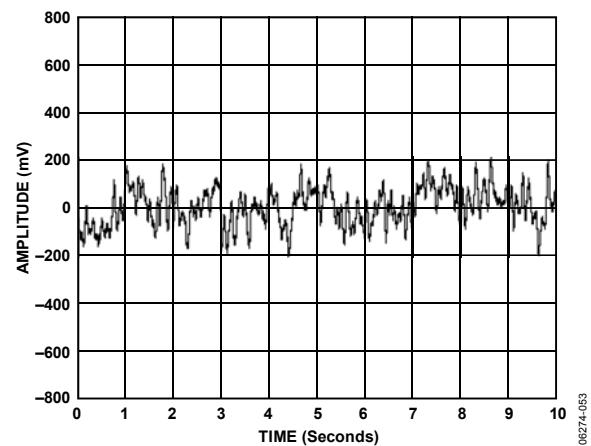
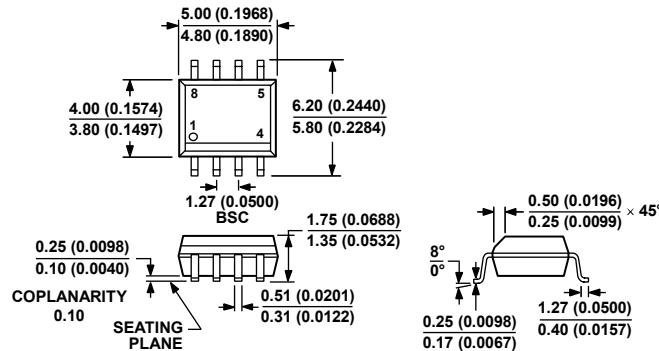


Figure 51. Peak-to-Peak Noise,  $V_S \leq \pm 15 V$ ,  $A_V = 1 M$ ,  $R_L = 10 k\Omega$

# AD8599

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

060506A

Figure 52. 8-Lead Standard Small Outline Package [SOIC\_N]

Narrow Body (R-8)

Dimensions shown in millimeters and (inches)

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
AD8599ARZ <sup>1</sup>	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8
AD8599ARZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8
AD8599ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8

<sup>1</sup> Z = Pb-free part.

**AD8599**

## **NOTES**

**AD8599**

**NOTES**